

Data Sheet January 2000 File Number 3552.3

## 30A, 200V Ultrafast Dual Diode

The RURG3020CC is an ultrafast dual diode with soft recovery characteristics ( $t_{rr}$  < 45ns). It has low forward voltage drop and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

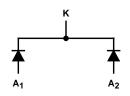
Formerly developmental type TA09645.

## **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURG3020CC	TO-247	RURG3020C

NOTE: When ordering, use the entire part number.

## Symbol



#### **Features**

Ultrafast with Soft Recovery	<45ns
Operating Temperature	175 <sup>0</sup> C
Reverse Voltage	.200V

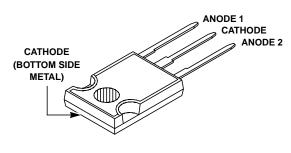
- Avalanche Energy Rated
- Planar Construction

## **Applications**

- · Switching Power Supplies
- Power Switching Circuits
- · General Purpose

## **Packaging**

#### **JEDEC STYLE TO-247**



Absolute Maximum Ratings (Per Leg) T <sub>C</sub> = 25°C		
	RURG3020CC	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	200	V
Working Peak Reverse Voltage	200	V
DC Blocking Voltage	200	V
Average Rectified Forward Current (Per Leg)	30	Α
$(T_C = 145^{\circ}C)$		
Repetitive Peak Surge CurrentI <sub>FRM</sub>	70	Α
(Square Wave, 20kHz)		
Nonrepetitive Peak Surge Current	325	Α
(Halfwave, 1 Phase, 60Hz)		
Maximum Power Dissipation	125	W
Avalanche Energy (See Figures 7 and 8)	20	mJ
Operating and Storage Temperature	-65 to 175	οС

**Electrical Specifications** (Per Leg) T<sub>C</sub> = 25°C, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 30A	-	-	1.0	V
	$I_F = 30A, T_C = 150^{\circ}C$	-	-	0.85	V
I <sub>R</sub>	V <sub>R</sub> = 200V	-	-	250	μА
	V <sub>R</sub> = 200V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1	mA
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 100A/\mu s$	-	-	45	ns
	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	-	50	ns
t <sub>a</sub>	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	20	-	ns
t <sub>b</sub>	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	15	-	ns
$R_{ heta JC}$		-	-	1.2	°C/W

#### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

 $I_R$  = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 6), summation of  $t_a + t_b$ .

t<sub>a</sub> = Time to reach peak reverse current (See Figure 6).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**

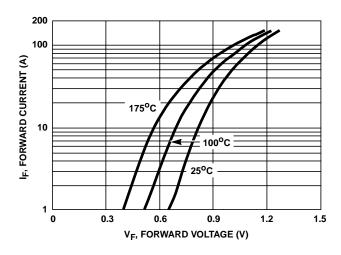


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

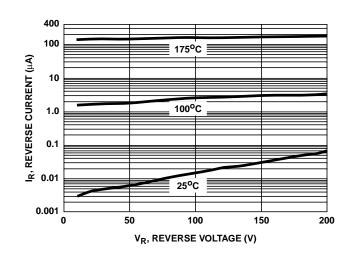


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

## Typical Performance Curves (Continued)

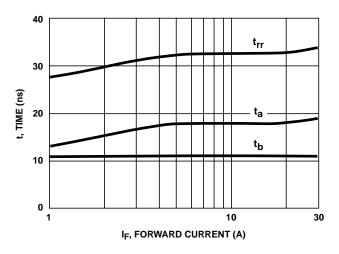


FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

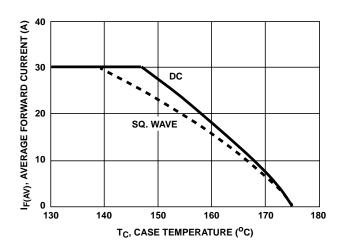


FIGURE 4. CURRENT DERATING CURVE

### Test Circuits and Waveforms

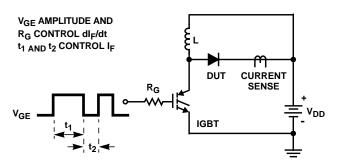


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

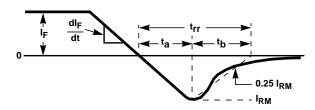


FIGURE 6. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

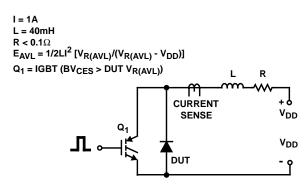


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

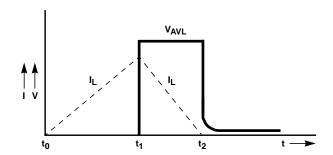


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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